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CONFIRMATION NO. 2202

<b>SERIAL NUMBER</b> 10/512,022	<b>FILING OR 371(c) DATE</b> 10/19/2004 <b>RULE</b>	<b>CLASS</b> 117	<b>GROUP ART UNIT</b> 1765	<b>ATTORNEY DOCKET NO.</b> 93120
<b>APPLICANTS</b> Tetsuhiro Iida, Hiratsuka-shi, JAPAN; Yutaka Shiraishi, Hiratsuka-shi, JAPAN; Ryota Suewaka, Hiratsuka-shi, JAPAN; Junsuke Tomioka, Hiratsuka-shi, JAPAN;				
<b>** CONTINUING DATA *****</b> This application is a 371 of PCT/JP03/04868 04/17/2003				
<b>** FOREIGN APPLICATIONS *****</b> JAPAN 2002-118281 04/19/2002				
Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Verified and Acknowledged <i>A. Iida</i> <i>54</i> Examiner's Signature Initials		<b>STATE OR COUNTRY</b> JAPAN	<b>SHEETS DRAWING</b> 8	<b>TOTAL CLAIMS</b> 16
			<b>INDEPENDENT CLAIMS</b> 7	
<b>ADDRESS</b> 24628				
<b>TITLE</b> Single crystal silicon producing method, single crystal silicon wafer producing method, seed crystal for producing single crystal silicon, single crystal silicon ingot, and single crystal silicon wafer				
<b>FILING FEE RECEIVED</b> 1432	<b>FEES:</b> Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time ) <input type="checkbox"/> 1.18 Fees ( Issue ) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit	